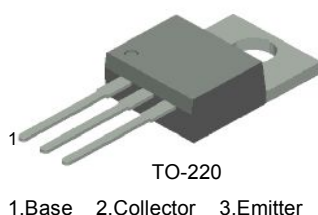


FJP5555

NPN Silicon Transistor

High Voltage Switch Mode Application

- Fast Speed Switching
- Wide Safe Operating Area
- Suitable for Electronic Ballast Application



Absolute Maximum Ratings * $T_C=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
BV_{CBO}	Collector-Base Voltage	1050	V
BV_{CEO}	Collector-Emitter Voltage	400	V
BV_{EBO}	Emitter-Base Voltage	14	V
I_C	Collector Current (DC)	5	A
I_{CP}	Collector Current (Pulse)	10	A
P_C	Collector Dissipation.	85	W
T_J	Junction Temperature	150	$^{\circ}\text{C}$
T_{STG}	Storage Junction Temperature Range	- 55 ~ 150	$^{\circ}\text{C}$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Ordering Information

Part Number	Marking	Package	Packing Method	Remarks
FJP5555TU	J5555	TO220	TUBE	

Electrical Characteristics * $T_C=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C=500\mu\text{A}$, $I_E=0$	1050			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C=5\text{mA}$, $I_B=0$	400			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E=500\mu\text{A}$, $I_C=0$	14			V
h_{FE}	* DC Current Gain	$V_{CE}=5\text{V}$, $I_C=10\text{mA}$	10			
		$V_{CE}=3\text{V}$, $I_C=0.8\text{A}$	20		40	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=1\text{A}$, $I_B=0.2\text{A}$			0.5	V
		$I_C=3.5\text{A}$, $I_B=1.0\text{A}$			1.5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C=3.5\text{A}$, $I_B=1.0\text{A}$			1.2	V
C_{ob}	Output Capacitance	$V_{CB}=10\text{V}$, $f=1\text{MHz}$		45		pF
t_{ON}	Turn On Time	$V_{CC}=125\text{V}$, $I_C=0.5\text{A}$ $I_{B1}=45\text{mA}$, $I_{B2}=0.5\text{A}$ $R_L=250\Omega$			1.0	μs
t_{STG}	Storage Time				1.2	μs
t_F	Fall Time				0.3	μs
t_{ON}	Turn On Time	$V_{CC}=250\text{V}$, $I_C=2.5\text{A}$ $I_{B1}=0.5\text{A}$, $I_{B2}=1.0\text{A}$ $R_L=100\Omega$			2.0	μs
t_{STG}	Storage Time				2.5	μs
t_F	Fall Time				0.3	μs
EAS	Avalanche Energy	$L=2\text{mH}$	6			mJ

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Characteristics

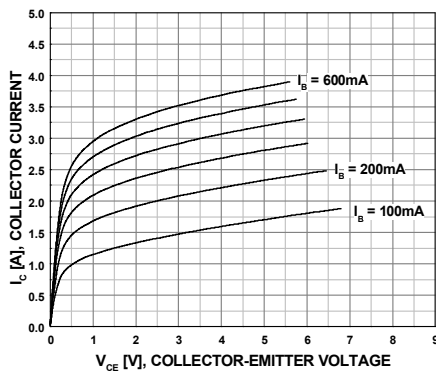


Figure 1. Static Characteristics

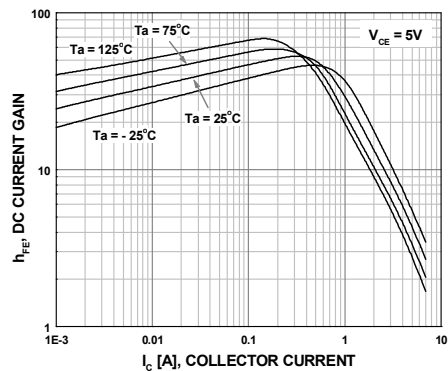


Figure 2. DC Current Gain

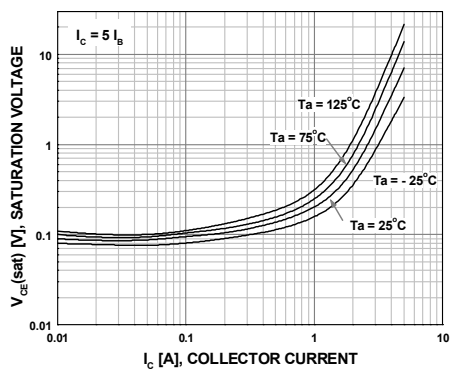


Figure 3. Saturation Voltage

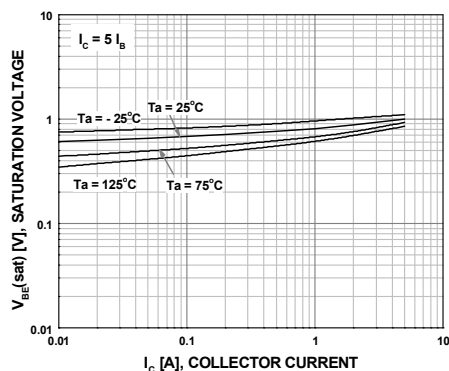


Figure 4. Saturation Voltage

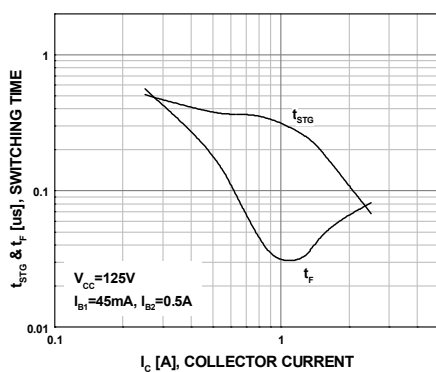


Figure 5. Resistive Load Switching

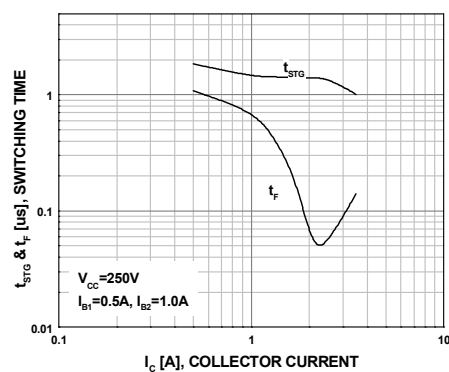


Figure 6. Resistive Load Switching

Typical Characteristics (Continued)

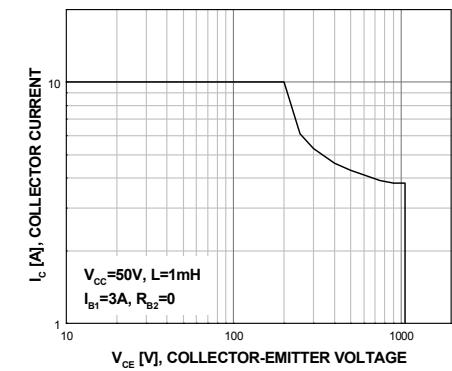


Figure 7. Reverse Biased Safe Operating Area

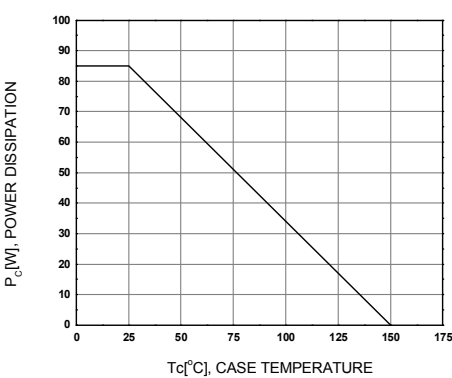


Figure 8. Power Derating

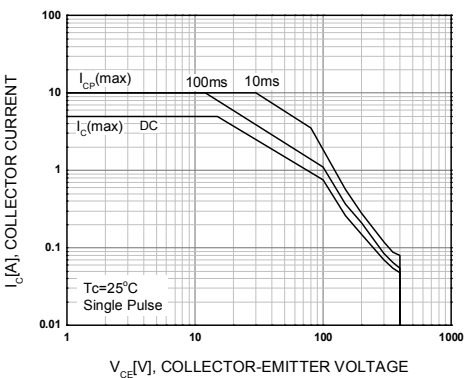
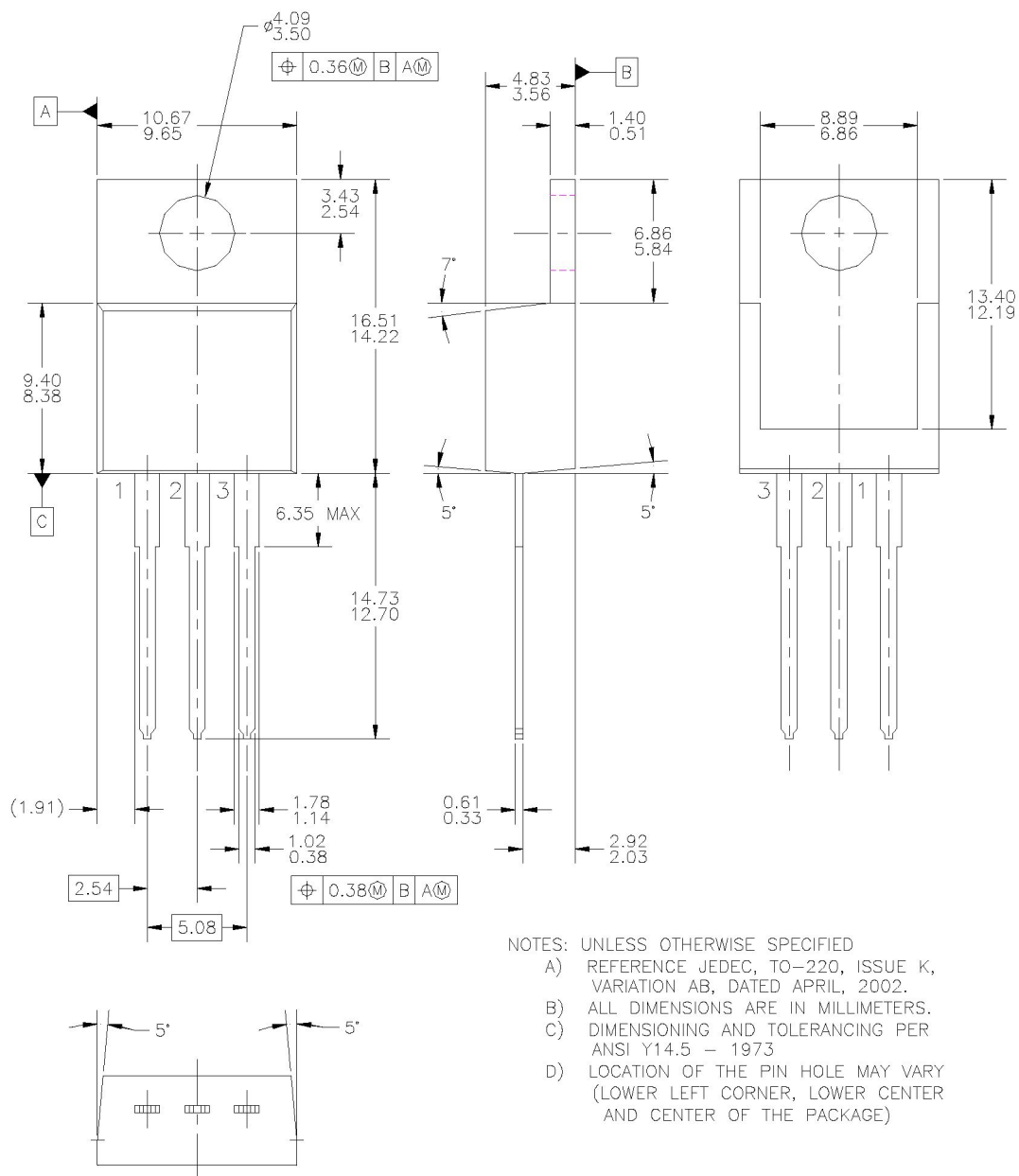


Figure 9. Forward Biased Safe Operating Area

Mechanical Dimensions

TO220



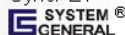


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